

Product data sheet

Product profile

1.1 General description

The BB181LX is a planar technology variable capacitance diode in a SOD882T ultra small leadless plastic SMD package.

1.2 Features

- Excellent linearity
- Ultra small leadless SMD package
- C_{d(28V)}: 1 pF; ratio: 14

1.3 Applications

- Voltage Controlled Oscillators (VCO)
- Electronic tuning in satellite tuners
- Tunable coupling

Pinning information 2.

Table 1. **Pinning**

Pin	Description	Simplified outline	Graphic symbol
1	cathode	[1]	٦L
2	anode	1 2	₩
		Transparent top view	

^[1] The marking bar indicates the cathode.

3. **Ordering information**

Table 2. **Ordering information**

Type number	Package				
	Name	Description	Version		
BB181LX	-	leadless ultra small plastic package; 2 terminals; body 1 $\times0.6\times0.4$ mm	SOD882T		





4. Marking

Table 3. Marking codes

Type number	Marking code
BB181LX	L6

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{R}	reverse voltage		-	32	V
I _F	forward current		-	20	mA
T _{stg}	storage temperature		-55	+150	°C
Tj	junction temperature		-55	+125	°C

6. Characteristics

Table 5. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _R	reverse current	see Figure 3				
		V _R = 30 V	-	-	10	nA
		$V_R = 30 \text{ V}; T_j = 85 ^{\circ}\text{C}$	-	-	200	nA
r _s	diode series resistance	$f = 470 \text{ MHz}$ at $C_d = 9 \text{ pF}$; see Figure 2	-	2.0	-	Ω
C _d	diode capacitance	f = 1 MHz; see <u>Figure 1</u> and <u>Figure 4</u>				
		$V_{R} = 0.5 V$	8	-	17	pF
		V _R = 28 V	0.7	-	1.055	pF
C _{d(0V5)} /C _{d(28V)}	diode capacitance ratio (0.5 V to 28 V)	f = 1 MHz	12	-	16	

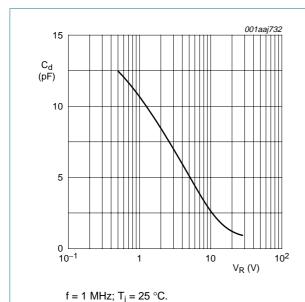


Fig 1. Diode capacitance as a function of reverse voltage; typical values

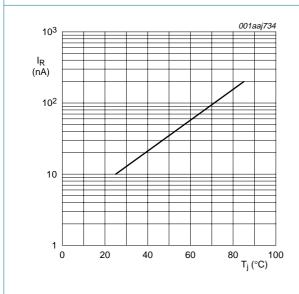


Fig 3. Reverse current as a function of junction temperature; maximum values

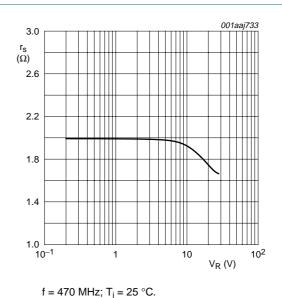
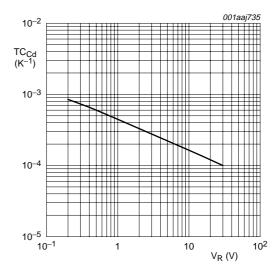


Fig 2. Diode serial resistance as a function of reverse voltage; typical values



 $T_i = 0$ °C to 85 °C.

Fig 4. Temperature coefficient of diode capacitance as a function of reverse voltage; typical values

7. Package outline

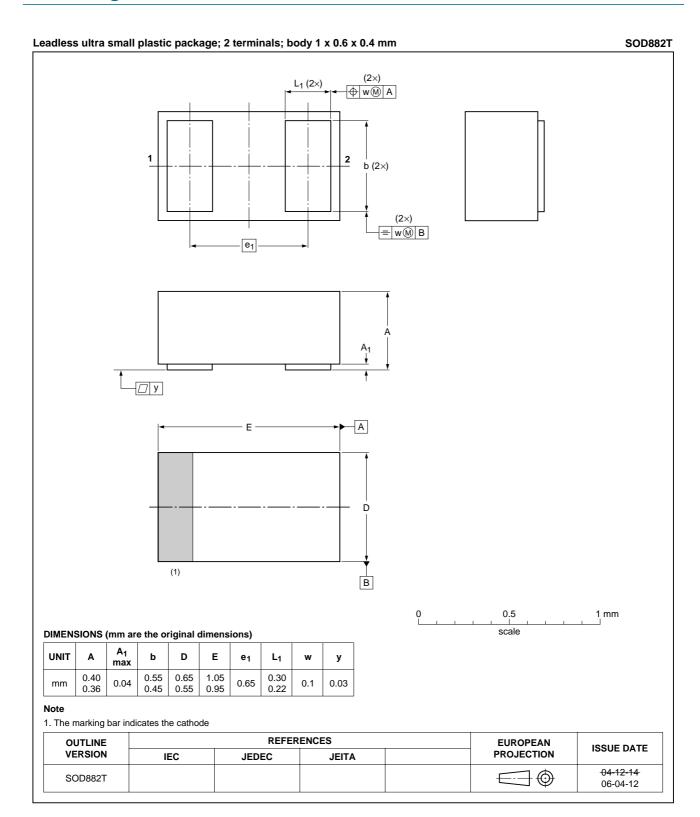


Fig 5. Package outline SOD882T



8. Abbreviations

Table 6. Abbreviations

Acronym	Description
SMD	Surface Mounted Device
VHF	Very High Frequency

9. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BB181LX_1	20090219	Product data sheet	-	-

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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BB181LX NXP Semiconductors

VHF variable capacitance diode

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